NSL12AWT1G

High Current Surface Mount PNP Silicon Low V_{CE(sat)} Transistor for Battery Operated Applications

Features

• High Current Capability (3 A)

MAXIMUM BATINGS (T. - 25°C)

- High Power Handling (Up to 650 mW)
- Low V_{CE(s)} (170 mV Typical @ 1 A)
- Small Size
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Benefits

- High Specific Current and Power Capability Reduces Required PCB Area
- Reduced Parasitic Losses Increases Battery Life

$\frac{1}{1} = 25.0$					
Rating	Symbol	Max	Unit		
Collector-Emitter Voltage	V _{CEO}	-12	Vdc		
Collector-Base Voltage	V _{CBO}	-12	Vdc		
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc		
Collector Current – Continuous – Peak	I _C I _{CM}	-2.0 -3.0	Adc		
Electrostatic Discharge	ESD	HBM Class 3 MM Class C			

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Max 450 3.6	Unit mW mW/°C
3.6	mW/°C
275	°C/W
650	mW
5.2	mW/°C
192	°C/W
105	°C/W
1.4	W
–55 to +150	°C
_	

1. FR-4, Minimum Pad, 1 oz Coverage

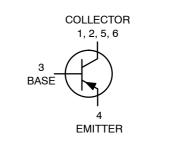
2. FR-4, 1" Pad, 1 oz Coverage



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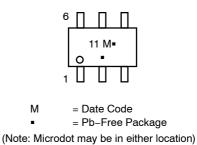
12 VOLTS 3.0 AMPS PNP TRANSISTOR





SC-88/SOT-363 CASE 419B STYLE 20

MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

NSL12AWT1G

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Мах	Unit
OFF CHARACTERISTICS	·				
Collector – Emitter Breakdown Voltage, ($I_C = -10 \text{ mAdc}, I_B = 0$)	V _{(BR)CEO}	-12	-15	-	Vdc
Collector – Base Breakdown Voltage, ($I_C = -0.1 \text{ mAdc}, I_E = 0$)	V _{(BR)CBO}	-12	-25	-	Vdc
Emitter – Base Breakdown Voltage, ($I_E = -0.1 \text{ mAdc}, I_C = 0$)	V _{(BR)EBO}	-5.0	-7.0	-	Vdc
Collector Cutoff Current, ($V_{CB} = -12$ Vdc, $I_E = 0$)	I _{CBO}	-	-0.02	-0.1	μAdc
Collector–Emitter Cutoff Current, ($V_{CES} = -12 \text{ Vdc}, I_E = 0$)	I _{CES}	-	-0.03	-0.1	μAdc
Emitter Cutoff Current, (V _{CES} = -5.0 Vdc, I _E = 0)	I _{EBO}	-	-0.03	-0.1	μAdc
ON CHARACTERISTICS					
DC Current Gain (Note 3) ($I_C = -0.5 \text{ A}, V_{CE} = -1.5 \text{ V}$) ($I_C = -0.8 \text{ A}, V_{CE} = -1.5 \text{ V}$) ($I_C = -1.0 \text{ A}, V_{CE} = -1.5 \text{ V}$)	h _{FE}	100 100 100	180 165 160	_ 300 _	
Collector – Emitter Saturation Voltage (Note 3) ($I_C = -0.5 \text{ A}, I_B = -10 \text{ mA}$) ($I_C = -0.8 \text{ A}, I_B = -16 \text{ mA}$) ($I_C = -1.0 \text{ A}, I_B = -20 \text{ mA}$)	V _{CE(sat)}		-0.10 -0.14 -0.17	-0.160 -0.235 -0.290	V

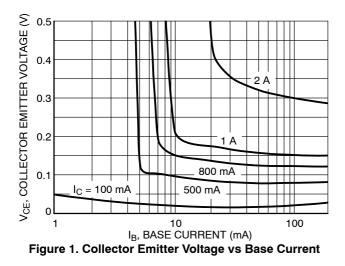
$(I_C = -0.8 \text{ A}, I_B = -16 \text{ mA})$ $(I_C = -1.0 \text{ A}, I_B = -20 \text{ mA})$		- -	-0.14 -0.17	-0.235 -0.290	
Base – Emitter Saturation Voltage (Note 3) $(I_{\rm C}$ = -1.0 A, $I_{\rm B}$ = -20 mA)	V _{BE(sat)}	_	-0.84	-0.95	V
Base – Emitter Turn–on Voltage (Note 3) (I _C = –1.0 A, V _{CE} = –1.5 V)	V _{BE(on)}	_	-0.81	-0.95	V
Cutoff Frequency (I _C = -100 mA, V _{CE} = -5.0 V, f = 100 MHz)	fT	-	100	-	MHz
Output Capacitance ($V_{CB} = -1.5 \text{ V}, \text{ f} = 1.0 \text{ MHz}$)	C _{obo}	-	50	65	pF

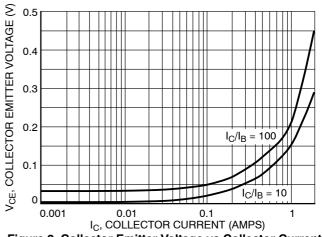
3. Pulsed Condition: Pulse Width < 300 μ sec, Duty Cycle < 2%

ORDERING INFORMATION

Device	Package	Shipping [†]
NSL12AWT1G	SOT–363 (Pb–Free)	3000 Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.







NSL12AWT1G

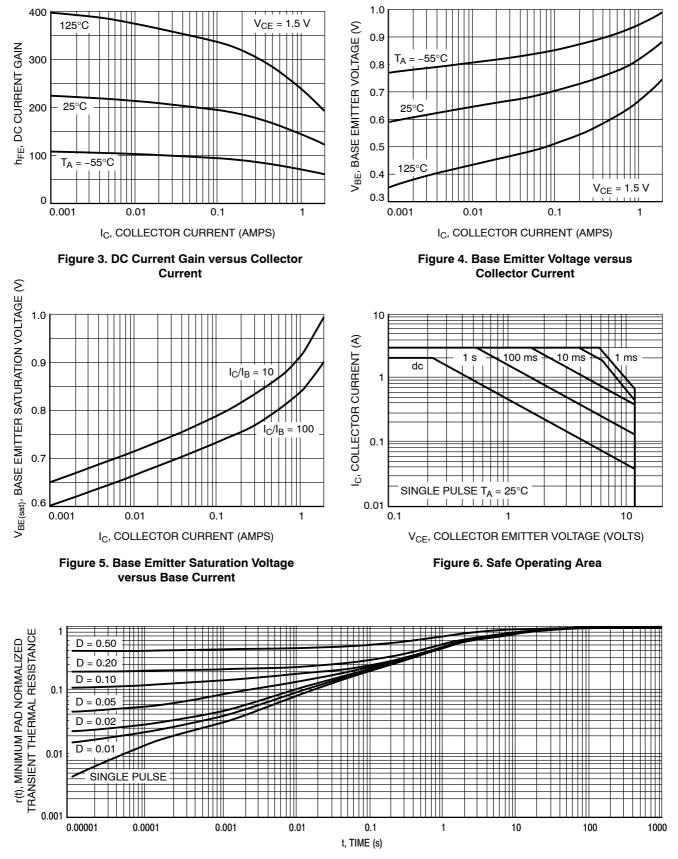


Figure 7. Normalized Thermal Response

PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363

CASE 419B-02 **ISSUE W**

NOTES

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

CONTROLLING DIMENSION: INCH. 2.

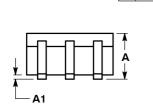
419B-01 OBSOLETE, NEW STANDARD 419B-02.

	MIL	LIMETE	RS	INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.95	1.10	0.031	0.037	0.043
A1	0.00	0.05	0.10	0.000	0.002	0.004
A3	0.20 REF			0.008 REF		
b	0.10	0.21	0.30	0.004	0.008	0.012
С	0.10	0.14	0.25	0.004	0.005	0.010
D	1.80	2.00	2.20	0.070	0.078	0.086
E	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65 BSC			0.026 BSC		
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	2.00	2.10	2.20	0.078	0.082	0.086

STYLE 20: PIN 1. COLLECTOR

- 2. COLLECTOR 3. BASE
- 4. EMITTER 5. COLLECTOR

5. 6 COLLECTOR



D

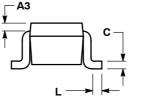
-E-

b 6 PL

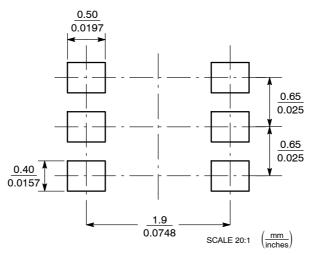
0.2 (0.008) M E M

 \oplus

HE



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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